

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
60V	8.5mΩ@10V	40A
	10.0mΩ@4.5V	



合肥矽普半导体

Siliup Semiconductor Technology Co., Ltd

技术 品质 服务

www.siliup.com

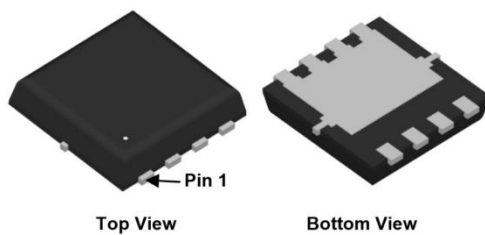
Feature

- Fast Switching
- Low Gate Charge and Rdson
- Advanced Split Gate Trench Technology
- 100% Single Pulse avalanche energy Test

Applications

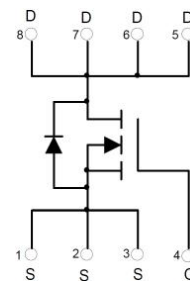
- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

Package

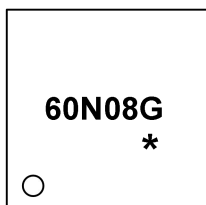


PDFN3X3-8L

Circuit diagram



Marking



60N08G
*

:Device Code
:Month Code

Order Information

Device	Package	Unit/Tape
SP60N08GNJ	PDFN3X3-8L	5000

Absolute maximum ratings (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	60	V
Gate-Source Voltage	V_{GSS}	± 20	V
Continuous Drain Current (Tc=25°C)	I_D	40	A
Continuous Drain Current (Tc=100°C)	I_D	27	A
Pulse Drain Current Tested	I_{DM}	160	A
Single Pulse Avalanche Energy ¹	E_{AS}	90	mJ
Power Dissipation (Tc=25°C)	P_D	40	W
Power Dissipation (Tc=100°C)	P_D	16	W
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	3.13	°C/W
Maximum Junction Temperature	T_J	-55 to 150	°C
Storage Temperature Range	T_{STG}	-55 to 150	°C

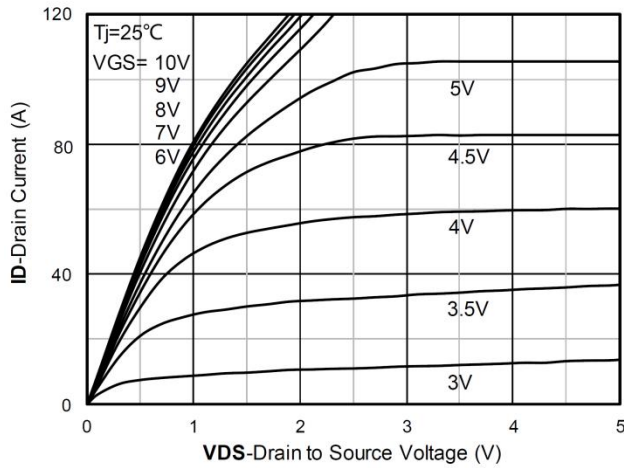
Electrical characteristics (Ta=25°C, unless otherwise noted)

Characteristics	Symbol	Test Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V, ID=250uA	60	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=48V, VGS=0V	-	-	1	uA
Gate Leakage Current	IGSS	VGS=±20V, VDS=0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	VDS=VGS, ID=250uA	1.1	1.5	2.1	V
Drain-Source On-state Resistance	RDS(ON)	VGS=10V, ID=20A	-	8.5	11.5	mΩ
		VGS=4.5V, ID=10A	-	10.0	14.5	
Gate Resistance	RG	VDS=30V , VGS=0V , f=1MHz	-	2.1	-	Ω
Dynamic Characteristics						
Input Capacitance	Ciss	VGS=0V, VDS=30V,F=1MHz	-	998	-	pF
Output Capacitance	Coss		-	242	-	
Reverse Transfer Capacitance	Crss		-	11	-	
Total Gate Charge	Qg	VDS=30V, VGS=10V, ID=20A	-	14	-	nC
Gate-Source Charge	Qgs		-	3	-	
Gate-Drain Charge	Qgd		-	3.5	-	
Gate Plateau Voltage	Vplateau		-	3.7	-	V
Switching Characteristics						
Turn-On Delay Time	td(on)	VDD=30V, ID=20A, VGS=10V, RG=4.7Ω	-	7	-	nS
Rise Time	tr		-	4	-	
Turn-Off Delay Time	td(off)		-	23	-	
Fall Time	tf		-	4	-	
Drain-Source Body Diode Characteristics						
Source-Drain Diode Forward Voltage	VSD	VGS=0V , IS=1A , TJ=25℃	-	-	1.2	V
Maximum Body-Diode Continuous Current	IS		-	-	40	A
Reverse Recovery Time	Trr	IS=30 A,di/dt=100 A/μs, TJ=25℃	-	36	-	nS
Reverse Recovery Charge	Qrr		-	23	-	nC

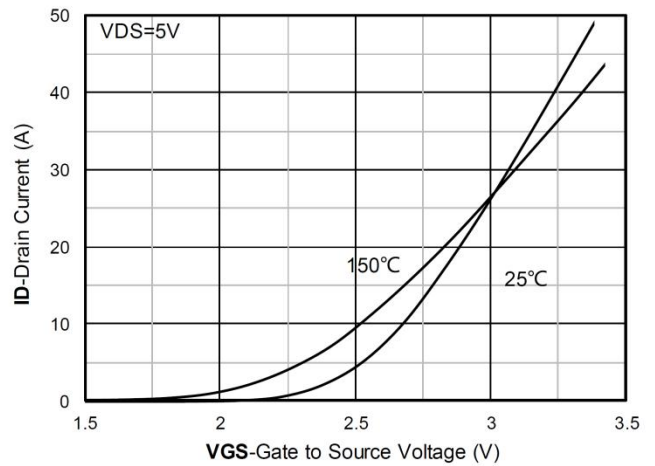
Note :

1. The test condition is $V_{DD}=30V, V_{GS}=10V, L=0.5mH, R_G=25\Omega$;

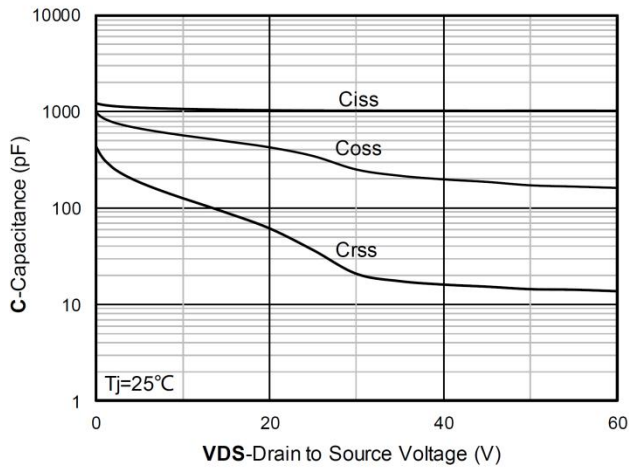
Typical Characteristics



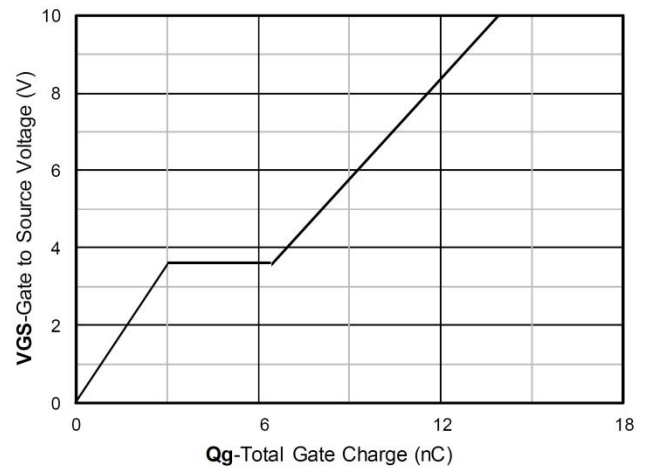
Output Characteristics



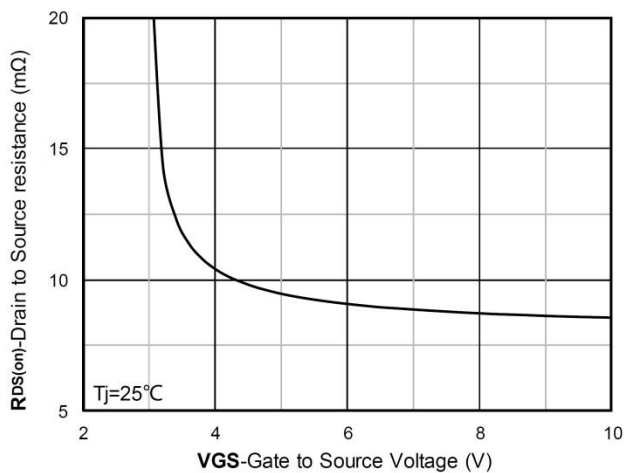
Transfer Characteristics



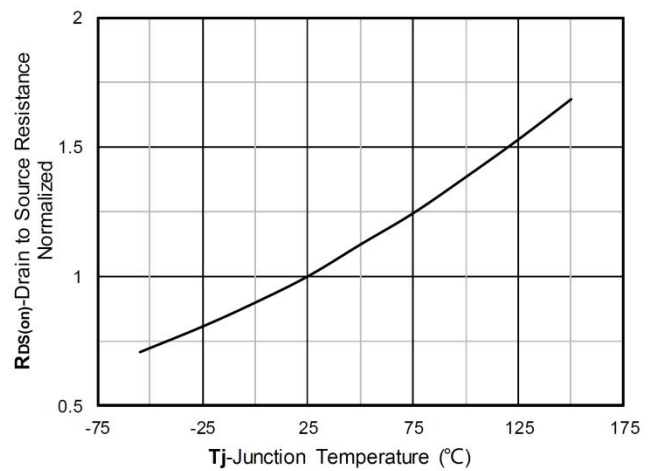
Capacitance Characteristics



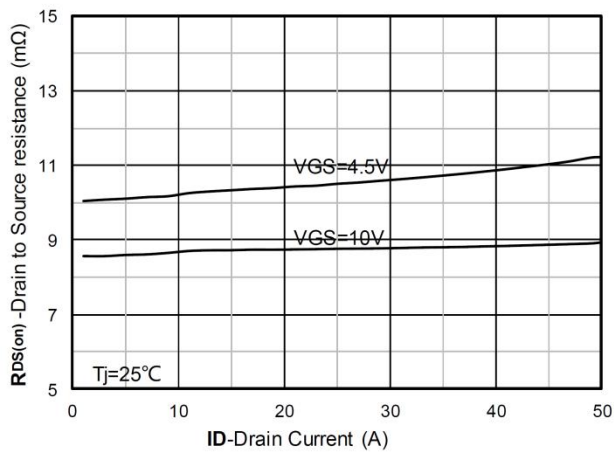
Gate Charge



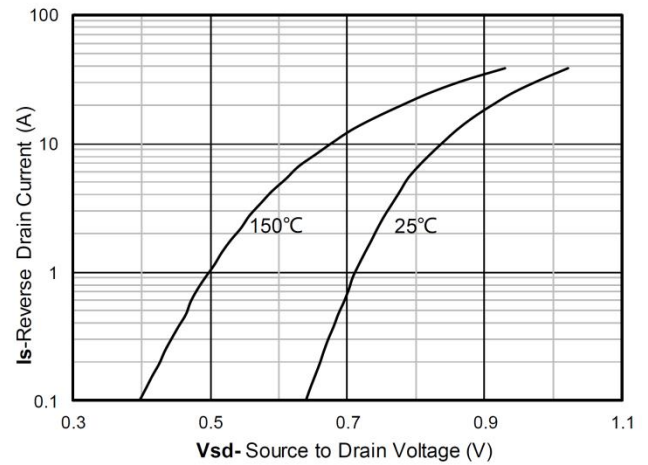
On-Resistance vs Gate to Source Voltage



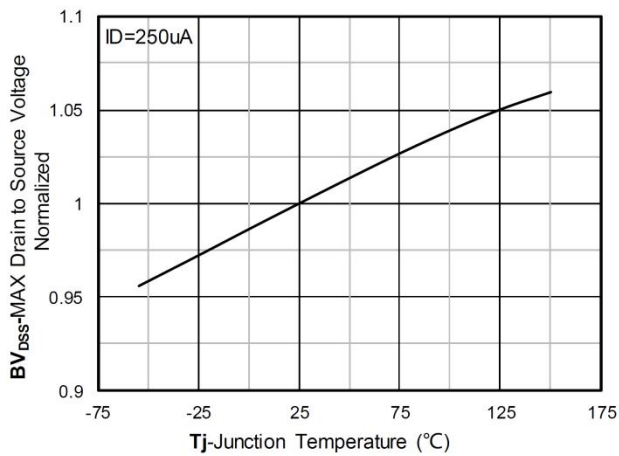
Normalized On-Resistance



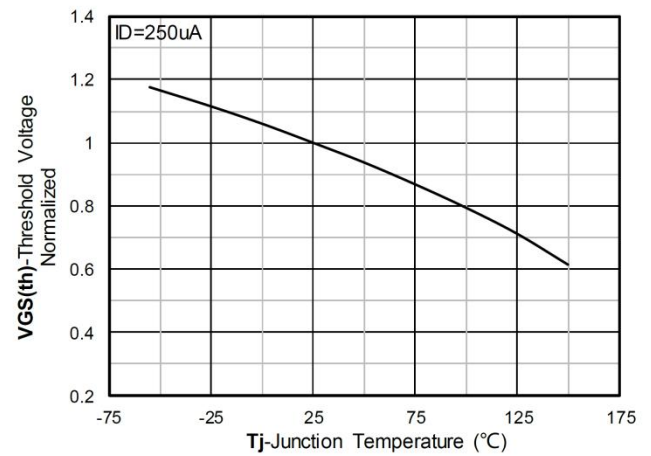
RDS(on) VS Drain Current



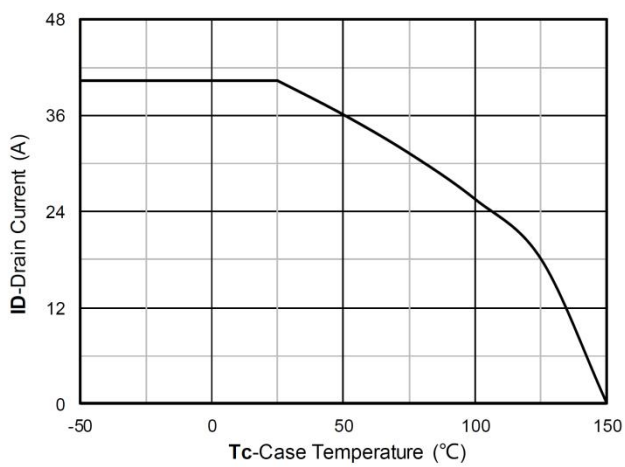
Forward characteristics of reverse diode



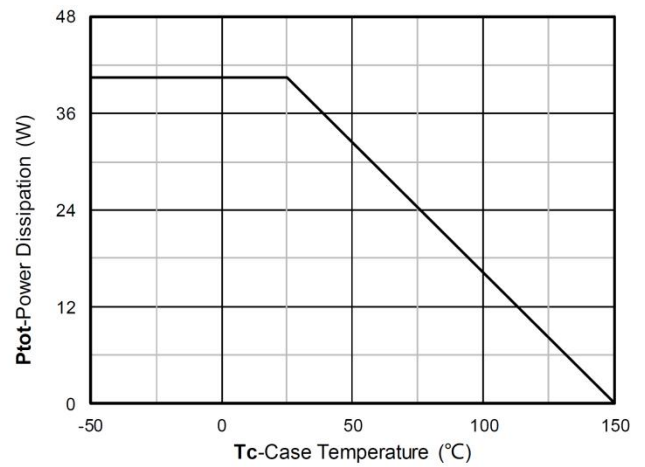
Normalized breakdown voltage



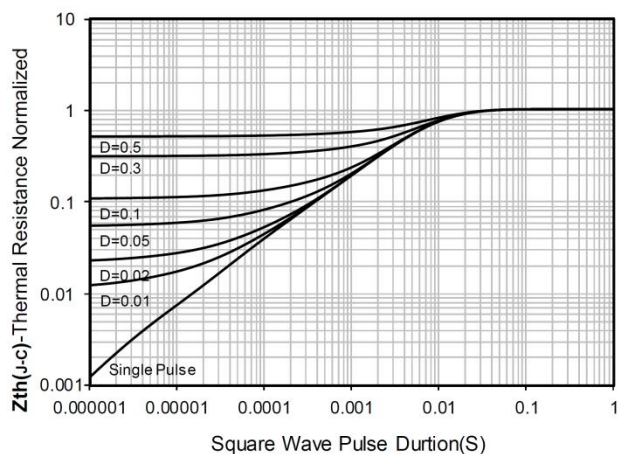
Normalized Threshold voltage



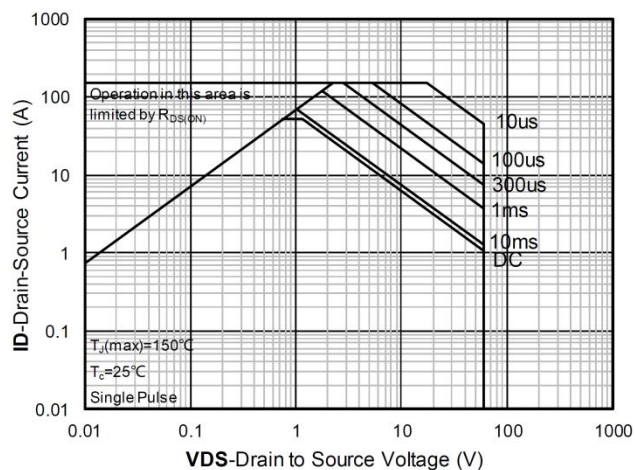
Current dissipation



Power dissipation



Normalized Maximum Transient Thermal Impedance

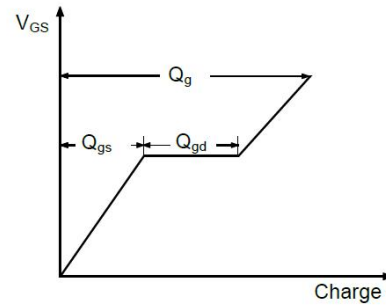
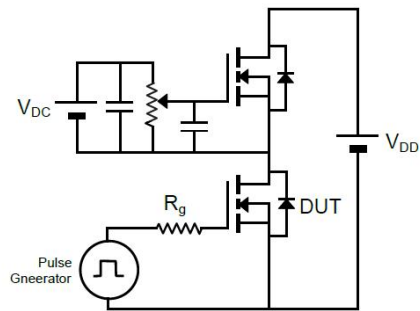


Safe Operation Area

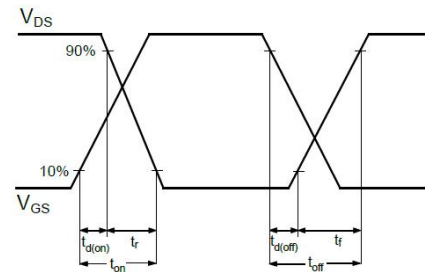
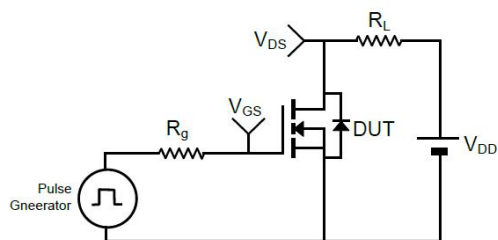


Test Circuit

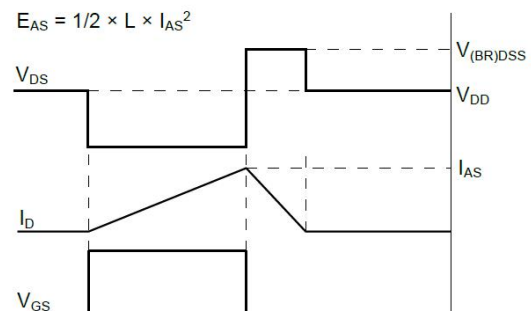
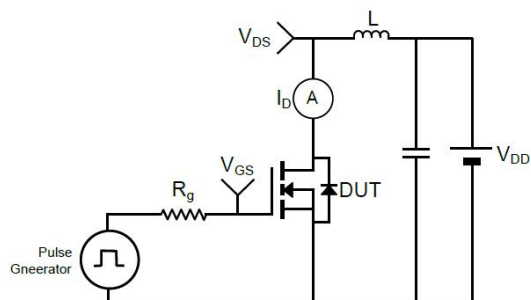
Gate Charge



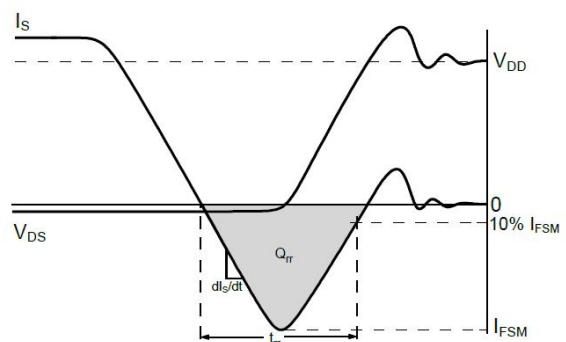
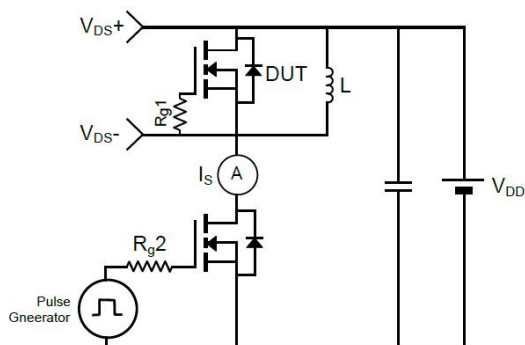
Resistive Load Switching Time



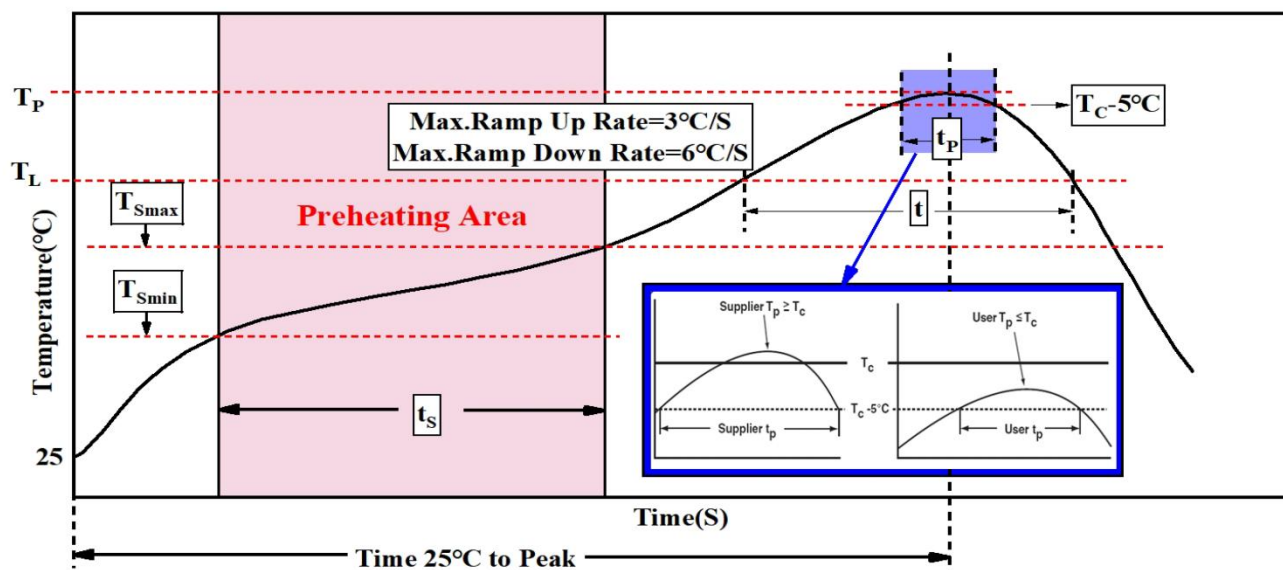
Un-clamped Inductive Load Switching



Drain-Source Body Diode Reverse Recovery



Temperature Profile for IR Reflow Soldering



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat & Soak		
Temperature min (T_{Smin})	100°C	150°C
Temperature max (T_{Smax})	150°C	200°C
Time (T_{Smin} to T_{Smax}) (t_s)	60-120 seconds	60-120 seconds
Average ramp-up rate (T_{Smax} to T_P)	3 °C/second max.	3°C/second max.
Liquidous temperature (T_L)	183 °C	217°C
Time at liquidous (t_L)	60-150 seconds	60-150 seconds
Peak package body Temperature e (T_P)*	See Classification Temp in table 1	See Classification Temp in table 2
Time (t_P)** within 5°C of the specified classification temperature (T_C)	20** seconds	30** seconds
Average ramp-down rate (T_P to T_{Smax})	6 °C/second max.	6 °C/second max.
Time 25°C to peak temperature	6 minutes max.	8 minutes max.
* Tolerance for peak profile Temperature (T_P) is defined as a supplier minimum and a user maximum. ** Tolerance for time at peak profile temperature (t_P) is defined as a supplier minimum and a user maximum		

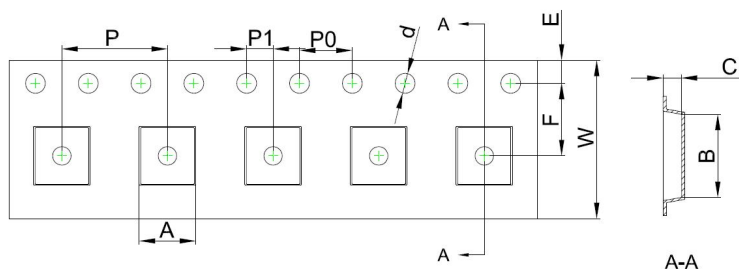
Table 1. SnPb Eutectic Process – Classification Temperatures (T_C)

Package Thickness	Volume mm ³ <350	Volume mm ³ ≥350
<2.5 mm	235 °C	220 °C
≥2.5 mm	220 °C	220 °C

Table 2. Pb-free Process – Classification Temperatures (T_C)

Package Thickness	Volume mm ³ <350	Volume mm ³ 350-2000	Volume mm ³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm – 2.5 mm	260 °C	250 °C	245 °C
≥2.5 mm	250 °C	245 °C	245 °C

PDFN3X3-8L Reel Information



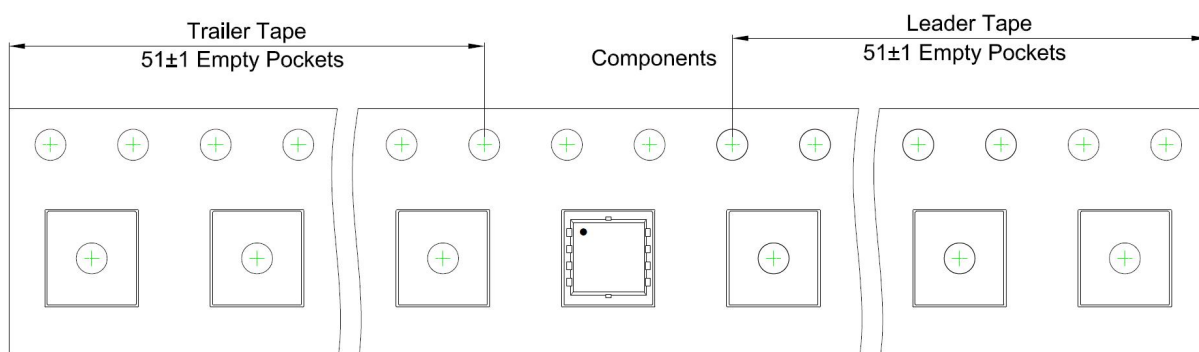
Packaging Description:

PDFN 3x3-8L parts are shipped in tape.

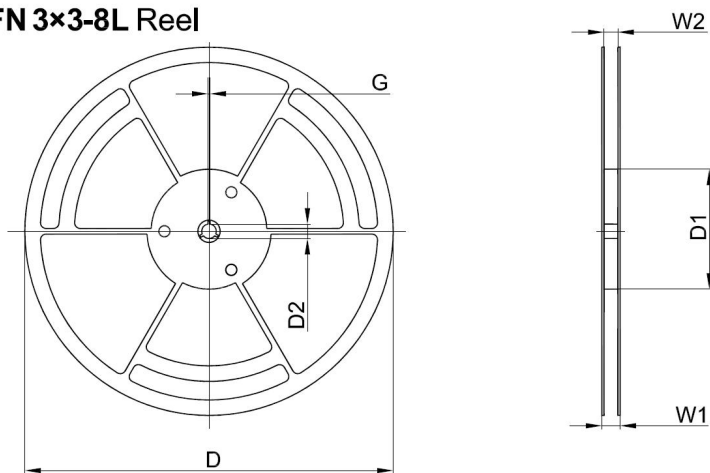
The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
PDFN3x3-8L	3.55	3.55	1.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

PDFN 3x3-8L Tape Leader and Trailer

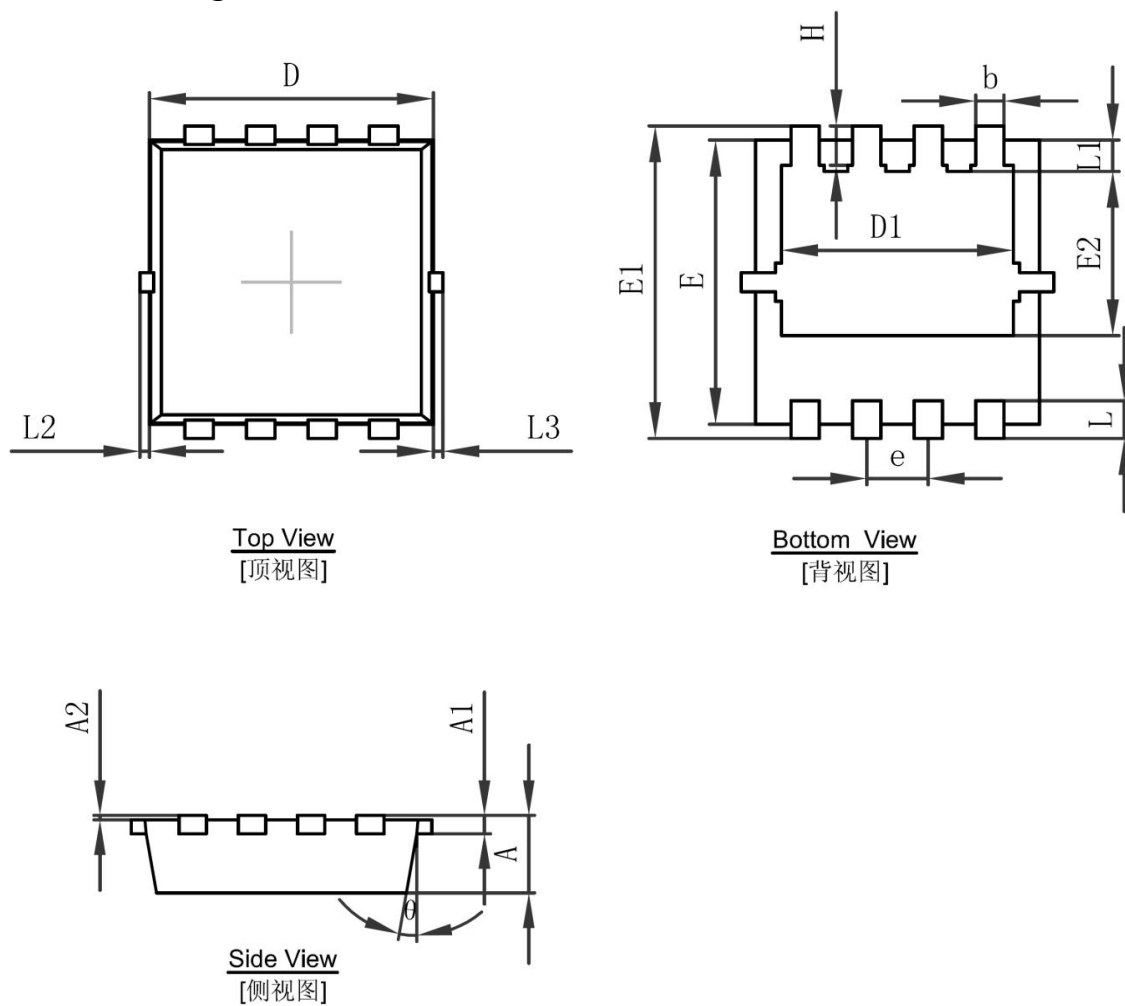


PDFN 3x3-8L Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	G	W1	W2
13"Dia	Ø330.00	100.00	13.00	1.90	17.60	12.40

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
5,000 pcs	13 inch	5,000 pcs	340×336×29	50,000 pcs	353×346×365

PDFN3X3-8L Package Information


Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.650	0.850
A1	0.152 REF.	
A2	0~0.05	
D	2.900	3.200
D1	2.300	2.600
E	2.900	3.100
E1	3.100	3.450
E2	1.535	1.935
b	0.200	0.400
e	0.550	0.750
L	0.300	0.500
L1	0.180	0.480
L2	0~0.100	
L3	0~0.100	
H	0.315	0.515
θ	9°	13°